

General Description

The WST6005 is the highest performance trench P-ch MOSFET with extreme high cell density, which provide excellent RDSON and gate charge for most of the small power switching and load switch applications.

The WST6005 meet the RoHS and Green Product requirement with full function reliability approved.

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent Cdv/dt effect decline
- Green Device Available

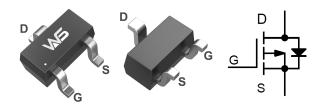
Product Summery

| BVDSS | RDSON ID | |
|-------|----------|--------|
| -20V | 280mΩ | -0.75A |

Applications

- High Frequency Point-of-Load Synchronous s Small power switching for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- Load Switch

SOT-523 Pin Configuration



Absolute Maximum Ratings

| Symbol | Parameter | Rating | Units | |
|--------------------------------------|--|------------|-------|--|
| V_{DS} | Drain-Source Voltage | -20 | V | |
| V_{GS} | Gate-Source Voltage | ±8 | V | |
| I _D @T _c =25℃ | Continuous Drain Current, V _{GS} @ -4.5V ¹ | -0.75 | Α | |
| I _D @T _c =70°C | Continuous Drain Current, V _{GS} @ -4.5V ¹ | -0.4 | Α | |
| I _{DM} | Pulsed Drain Current ² | -3 | Α | |
| P _D @T _A =25°C | Total Power Dissipation ³ | 0.175 | W | |
| T _{STG} | Storage Temperature Range -55 to 150 | | °C | |
| TJ | Operating Junction Temperature Range | -55 to 150 | ℃ | |

Thermal Data

| Symbol | Parameter | Тур. | Max. | Unit |
|----------------|--|------|------|------|
| $R_{	heta JA}$ | Thermal Resistance Junction-ambient ¹ | | 125 | °C/W |
| $R_{	heta JC}$ | Thermal Resistance Junction-Case ¹ | | 80 | °C/W |



Electrical Characteristics (T_J=25 °C, unless otherwise noted)

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Unit |
|--------------------------------------|--|--|-------|--------|------|------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V , I _D =-250uA | -20 | | | V |
| $\triangle BV_{DSS}/\triangle T_{J}$ | BVDSS Temperature Coefficient | Reference to 25 $^{\circ}$ C , I _D =-1mA | | -0.016 | | V/°C |
| | | V _{GS} =-4.5V , I _D =-0.45A | | 280 | 520 | |
| R _{DS(ON)} | Static Drain-Source On-Resistance ² | V _{GS} =-2.5V , I _D =-0.35A | | 360 | 750 | mΩ |
| | | V _{GS} =-1.8V , I _D =-0.25A | | 485 | 950 | |
| V _{GS(th)} | Gate Threshold Voltage | V _{GS} =V _{DS} , I _D =-250uA | -0.35 | -0.60 | -1 | V |
| $	riangle V_{GS(th)}$ | V _{GS(th)} Temperature Coefficient | | | 3.97 | | mV/℃ |
| | Drain Source Leakage Current | V _{DS} =-16V , V _{GS} =0V , T _J =25℃ | | | -1 | |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} =-16V , V _{GS} =0V , T _J =55℃ | | | -5 | uA |
| I _{GSS} | Gate-Source Leakage Current | $V_{GS}=\pm8V$, V_{DS} =0V | | | ±100 | nA |
| gfs | Forward Transconductance | V _{DS} =-5V , I _D =-1A | | 6.2 | | S |
| R_g | Gate Resistance | V _{DS} =0V , V _{GS} =0V , f=1MHz | | 9.5 | 12 | Ω |
| Qg | Total Gate Charge (-4.5V) | V _{DS} =-15V , V _{GS} =-4.5V , I _D =-1A | | 4 | 7.8 | |
| Q_gs | Gate-Source Charge | | | 0.52 | 1.0 | nC |
| Q_gd | Gate-Drain Charge | | | 1.15 | 2.0 | |
| $T_{d(on)}$ | Turn-On Delay Time | | | 10 | 8.0 | |
| T _r | Rise Time | V _{DD} =-15V , V _{GS} =-4.5V , | | 62 | 46 | ns |
| $T_{d(off)}$ | Turn-Off Delay Time | $R_G=3.3\Omega I_D=-1A$ | | 19 | 52 | |
| T _f | Fall Time | | | 18 | 24.8 | |
| C _{iss} | Input Capacitance | V _{DS} =-15V , V _{GS} =0V , f=1MHz | | 78 | 86 | |
| C _{oss} | Output Capacitance | | | 24 | 45 | pF |
| C _{rss} | Reverse Transfer Capacitance | | | 20 | 37 | |

Diode Characteristics

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Unit |
|-----------------|--|--|------|------|------|------|
| Is | Continuous Source Current ^{1,4} | V _G =V _D =0V , Force Current | | | -0.3 | Α |
| I _{SM} | Pulsed Source Current ^{2,4} | | | | -0.9 | Α |
| V_{SD} | Diode Forward Voltage ² | V_{GS} =0V , I_{S} =-1A , T_{J} =25 $^{\circ}$ C | | | -1.2 | V |
| t _{rr} | Reverse Recovery Time | lF=-0.5A,dI/dt=100A/μs,Tյ=25℃ | | 16 | | nS |
| Q _{rr} | Reverse Recovery Charge | | | 3.5 | | nC |

Note:

- 1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper, t<10 sec.
- 2.The data tested by pulsed , pulse width $\,\leq\,300\text{us}$, duty cycle $\,\leq\,2\%$
- 3.The power dissipation is limited by 150 $^{\circ}\mathrm{C}$ junction temperature
- 4. The data is theoretically the same as I_D and I_{DM} , in real applications, should be limited by total power dissipation.



Typical Characteristics

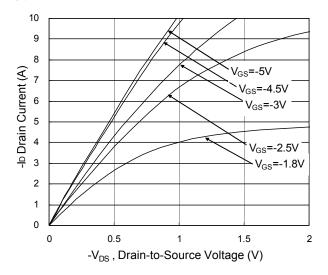


Fig.1 Typical Output Characteristics

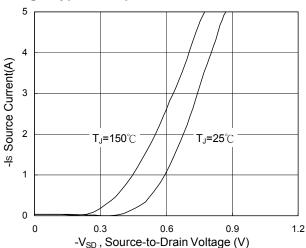


Fig.3 Forward Characteristics Of Reverse

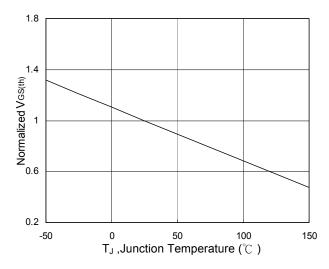


Fig.5 Normalized V_{GS(th)} vs. T_J

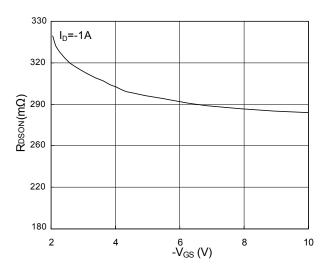


Fig.2 On-Resistance vs. Gate-Source

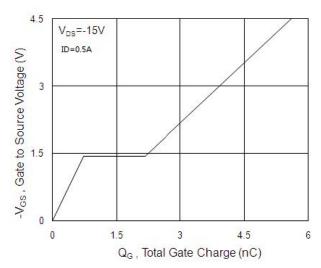


Fig.4 Gate-Charge Characteristics

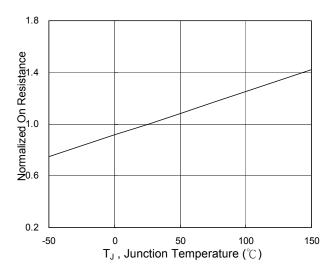
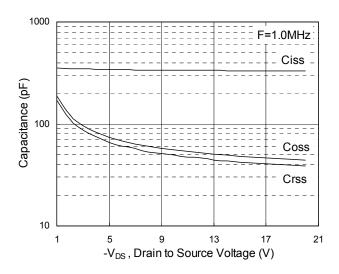


Fig.6 Normalized R_{DSON} vs. T_J





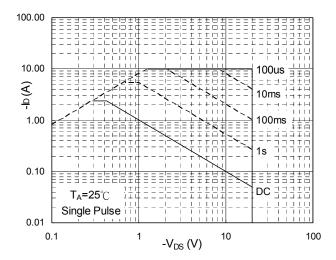


Fig.7 Capacitance

Fig.8 Safe Operating Area

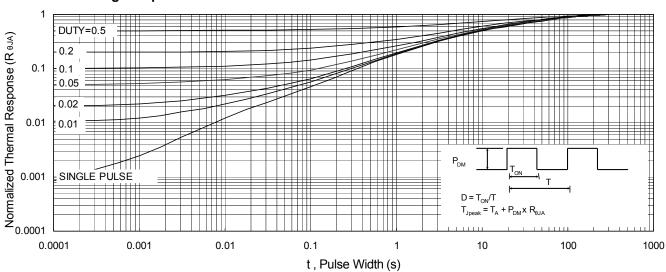


Fig.9 Normalized Maximum Transient Thermal Impedance

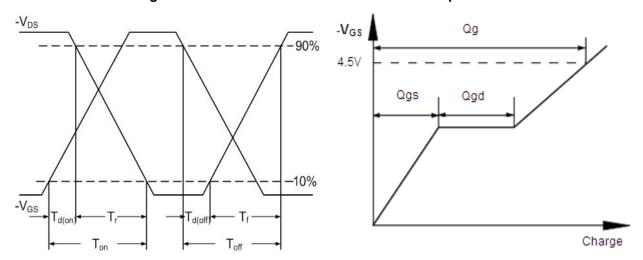


Fig.10 Switching Time Waveform

Fig.11 Gate Charge Waveform



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